Dark-state-induced heat rectification

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Heat and noise control is essential for the continued development of quantum technologies. For this purpose, a particularly powerful tool is the heat rectifier, which allows for heat transport in one configuration of two baths but not the reverse. Here we propose a class of rectifiers that exploits the unidirectionality of a low temperature bath to force the system into a dark state, thus blocking heat transport in one configuration of the two baths. However, if the two baths are switched around, a heat current is observed. An implementation using a qutrit coupled to two harmonic oscillators is proposed and rectification values beyond 10³ are achieved for realistic parameter values. Furthermore, we show that the heat current can be amplified by an order of magnitude through external driving without diminishing the diode functionality. The heat rectification effect is seen for a large range of parameters and it is robust towards both decay and dephasing.

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I. INTRODUCTION

With the advance of the second quantum revolution and an ever increased ability to exploit quantum effects, it is pertinent to understand and control noise and heat flow in modern quantum devices. It was even proposed that components like heat transistors [1-3] and heat diodes [4-6] could be used for a heat-based computer. Unsurprisingly, this increased attention resulted in a leap in understanding of both theoretical and experimental aspects of, e.g., heat engines [7–9] and information engines [10–12].

A particularly useful device for controlling heat is the heat rectifier: a device that exhibits asymmetric transport of heat similar to the diode in electronics. Within the framework of boundary-driven quantum systems, a quantum system is coupled to two heat baths at the extremities [13–15]. The diode properties of the quantum system can then be studied by calculating the heat transport for both configurations of the baths. Rectification has been found in a diverse set of models ranging from one [16–18] or two [19,20] two-level systems to large one-dimensional (1D) spin chains [21–25] and two-dimensional (2D) spin chain geometries [26]. It was even proposed to use quantum entanglement for enhanced rectification [27]. While large rectification factors have been found theoretically, recent proposals either required very large systems or were sensitive to decoherence [27,28].

Going from a qubit to a qutrit offers many additional engineering opportunities such as dark states [29–32]. With a large anharmonicity, the baths can be engineered to only promote transitions between a specific pair of levels [2,12,33]. At the same time, qutrits remain simple to construct since many qubits have additional levels [34-37], and therefore,

II. IDEALIZED VERSION

Here we propose a class of rectifiers consisting of three states coupled to two baths as seen in Figs. 1(a) and 1(b). In forward bias, the left bath is hot and the right bath is cold as seen in Fig. 1(a), while reverse bias is seen in Fig. 1(b). The system is engineered to exploit the unidirectionality of a cold bath to drive the system into the state $|D\rangle$ in reverse bias. $|D\rangle$ is a dark state of the right bath, and if it is populated, it will completely block any transport between the two baths. In forward bias, the two remaining states $|g\rangle$ and $|e\rangle$ facilitate transport as usual, thus implementing a perfect heat diode. The mechanism can easily be understood through the master equation $\partial_t \vec{P}(t) = W \vec{P}(t)$ where $\vec{P} = [P(|D\rangle), P(|g\rangle), P(|e\rangle)]^T$ is a vector of populations and W is a matrix of rates which generally takes the form

$$W = \begin{pmatrix} -\Gamma_{D \to g} - \Gamma_{D \to e} & \Gamma_{g \to D} & \Gamma_{e \to D} \\ \Gamma_{D \to g} & -\Gamma_{g \to D} - \Gamma_{g \to e} & \Gamma_{e \to g} \\ \Gamma_{D \to e} & \Gamma_{g \to e} & -\Gamma_{e \to D} - \Gamma_{e \to g} \end{pmatrix}.$$

Here $\Gamma_{a\to b}$ is the transition rate from $|a\rangle$ to $|b\rangle$. The left bath interaction is engineered such that, in reverse bias, the cold bath allows for transitions into the dark state but not out of it, i.e., $\Gamma_{D\to g}$, $\Gamma_{D\to e}=0$ and $\Gamma_{g\to D}$, $\Gamma_{e\to D}>0$. The other rates are kept general for now, but an example is given in Eq. (5). In reverse bias, the rate matrix becomes

$$W = \begin{pmatrix} 0 & \Gamma_{g \to D} & \Gamma_{e \to D} \\ 0 & -\Gamma_{g \to D} - \Gamma_{g \to e} & \Gamma_{e \to g} \\ 0 & \Gamma_{g \to e} & -\Gamma_{e \to D} - \Gamma_{e \to g} \end{pmatrix}.$$

they offer a great platform for studying open system dynamics and quantum thermodynamics.

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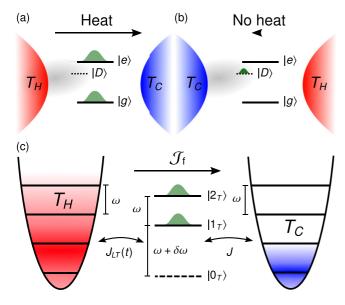


FIG. 1. (a,b) Minimal model for dark-state-induced rectification. (a) In forward bias, excitations are transported through the channel $|g\rangle \leftrightarrow |e\rangle$. (b) In reverse bias, the diode is closed by the dark state $|D\rangle$. (c) Possible model for dark-state-induced rectification consisting of a qutrit and two harmonic oscillators. The ground state acts as the dark state, which is isolated from the right bath due to energy conservation

In the long time limit, the system will go towards the steadystate solution $\partial_t \vec{P}_{ss} = 0$, which is easily found to be

$$P_{ss}(|D\rangle) = 1.$$

With one state fully populated no heat is transferred, and the system implements a perfect diode. To discuss the heat transferred in forward bias and to discuss one possible implementation of this idea, the example seen in Fig. 1(c) is studied.

III. SETUP

The Hamiltonian for the implementation shown in Fig. 1(c) is

$$\begin{split} \hat{H} &= \omega(\hat{a}_L^{\dagger}\hat{a}_L + \hat{a}_R^{\dagger}\hat{a}_R) + (\omega + \delta\omega)\hat{a}_T^{\dagger}\hat{a}_T \\ &- \frac{\delta\omega}{2}\hat{a}_T^{\dagger}\hat{a}_T(\hat{a}_T^{\dagger}\hat{a}_T - 1) \\ &+ J_{LT}(t)(\hat{a}_L + \hat{a}_L^{\dagger})(\hat{a}_T + \hat{a}_T^{\dagger}) + J(\hat{a}_T + \hat{a}_T^{\dagger})(\hat{a}_R + \hat{a}_R^{\dagger}), \end{split}$$

where the subscripts L, T, and R are used for the left harmonic oscillator, the qutrit, and the right harmonic oscillator, respectively. \hat{a}_{α} and $\hat{a}_{\alpha}^{\dagger}$ for $\alpha \in \{L, T, R\}$ are ladder operators. ω is the frequency of the oscillators and $\delta \omega$ is the anharmonicity of the qutrit. The left hopping is time dependent $J_{LT}(t) = J + J' \cos(\delta \omega t)$ and J sets the energyscale of the system. We are using units where $\hbar = k_B = 1$. Transforming into the interaction picture with respect to $\hat{H}_0 = \omega \sum_{\alpha \in \{L, T, R\}} \hat{a}_{\alpha}^{\dagger} \hat{a}_{\alpha}$, performing a rotating wave approximation, and concatenating the qutrit to the three lowest levels the Hamiltonian becomes

$$\begin{split} \hat{H}_I &= -\delta\omega |0_T\rangle \langle 0_T| + J_{LT}(t) (\hat{a}_L \hat{a}_T^\dagger + \hat{a}_L^\dagger \hat{a}_T) \\ &+ J(\hat{a}_T \hat{a}_P^\dagger + \hat{a}_T^\dagger \hat{a}_R), \end{split}$$

where we introduced the notation $|0_T\rangle$, $|1_T\rangle$, and $|2_T\rangle$ for the three qutrit states. The two harmonic oscillators act as the two bath in Figs. 1(a) and 1(b), Due to the baths the system is open and its state is described through the density matrix $\hat{\rho}$. The decay of the harmonic oscillator correlation functions is modeled through the Lindblad master equation [38,39]

$$\frac{d\hat{\rho}}{dt} = \mathcal{L}[\hat{\rho}] = -i[\hat{H}, \hat{\rho}] + \mathcal{D}_L[\hat{\rho}] + \mathcal{D}_R[\hat{\rho}], \tag{1}$$

where $[\bullet, \bullet]$ is the commutator, $\mathcal{L}[\hat{\rho}]$ is the Lindblad superoperator, and $\mathcal{D}_{L(R)}[\hat{\rho}]$ is a dissipative term describing the action of the left (right) bath

$$\mathcal{D}_{L(R)}[\hat{\rho}] = \Gamma(n_{L(R)} + 1) \left(\hat{a}_{L(R)} \hat{\rho} \hat{a}_{L(R)}^{\dagger} - \frac{1}{2} \{ \hat{a}_{L(R)}^{\dagger} \hat{a}_{L(R)}, \rho \} \right) + \Gamma n_{L(R)} \left(\hat{a}_{L(R)}^{\dagger} \hat{\rho} \hat{a}_{L(R)} - \frac{1}{2} \{ \hat{a}_{L(R)} \hat{a}_{L(R)}^{\dagger}, \rho \} \right), \quad (2)$$

where $\{ \bullet, \bullet \}$ is the the anticommutator. Γ is the coupling strength between the baths and harmonic oscillators and $n_{L(R)} = (e^{\omega/T_{L(R)}} - 1)^{-1}$ is the mean number of excitation in the left (right) harmonic oscillator in the absence of the qutrit. By forward bias, we denote the case where $n_L = n_H$ and $n_R = n_C$ and heat flows from left to right. By reverse bias, we denote the case where $n_L = n_C$ and $n_R = n_H$ and heat flows from right to left. We assume that $n_H > n_C$. After sufficient time the system will reach a steady state $\mathcal{L}[\hat{\rho}_{ss}] = 0$. Unless otherwise stated, we use $\delta \omega = 300J$, J' = 0.5J, $\Gamma = 10J$, $n_H = 0.5$, and $n_C = 0$. To study transport, we write the change in total energy of the system

$$0 = \frac{d\langle H \rangle_{ss}}{dt} = \left\langle \frac{d\hat{H}}{dt} \right\rangle_{ss} + \text{tr}\{\hat{H}\mathcal{D}_L[\hat{\rho}_{ss}]\} + \text{tr}\{\hat{H}\mathcal{D}_R[\hat{\rho}_{ss}]\},$$
(3)

where $\langle \bullet \rangle_{ss} = tr\{\bullet \hat{\rho}_{ss}\}$ is the steady-state expectation value and $tr\{\bullet\}$ is the trace over the entire Hilbert space. The first part is identified as the work, the second term is the heat increase due to the left bath, and the third term is the heat increase due to the right bath. From this, we define the two transport measures

$$\mathcal{J}_{L(R)} = \Gamma n_{L(R)} \langle \hat{a}_{L(R)} \hat{a}_{L(R)}^{\dagger} \rangle_{ss} - \Gamma (n_{L(R)} + 1) \langle \hat{a}_{L(R)}^{\dagger} \hat{a}_{L(R)} \rangle_{ss},$$
(4a)

$$W = \frac{J'\delta\omega}{2i} \langle \hat{a}_L \hat{a}_T^{\dagger} e^{-i\delta\omega t} - \hat{a}_L^{\dagger} \hat{a}_T e^{i\delta\omega t} \rangle_{ss}. \tag{4b}$$

Since the steady-state density matrix is independent of ω , we use the ω -independent excitation current $\mathcal{J}_{L(R)}$ instead of the heat current $\omega \mathcal{J}_{L(R)}$. Likewise, we will focus on the number of excitations added through work $\mathcal{W}/\delta\omega$. We used that ω , $\delta\omega\gg J$, J' such that the substitution $\hat{H}\to\hat{H}_0$ can be made in the second and third terms in Eq. (3). We define the forward bias excitation current to be $\mathcal{J}_{\rm f}=-\mathcal{J}_R$, while the reverse bias excitation current is $\mathcal{J}_{\rm r}=\mathcal{J}_L$. The quality of the diode is quantified using the rectification

$$\mathcal{R} = -\frac{\mathcal{J}_f}{\mathcal{J}_r},$$

which tends to infinity for a perfect diode. In summary, the system is designed using the methodology seen in Figs. 1(a) and 1(b). This is seen through the equivalences

$$|D\rangle \equiv |0_T\rangle, \quad |g\rangle \equiv |1_T\rangle, \quad |e\rangle \equiv |2_T\rangle.$$

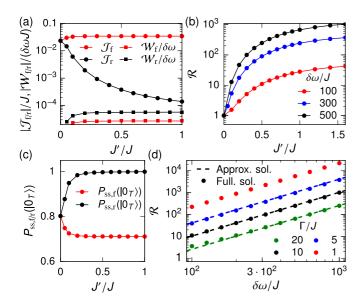


FIG. 2. (a) Excitation current and work as the diode is turned on through J'. (b) Rectification \mathcal{R} as a function of J' for different anharmonisities $\delta\omega$. (c) Steady-state population of the dark state as a function of J' for both forward and reverse bias. (d) Rectification as a function of the anharmonisity $\delta\omega$ for different values of Γ . The full solution is plotted using points and the approximate solution, Eq. (7), is plotted using a dashed line.

In forward bias, excitations can propagate through the system through transitions like

Forward:
$$|1_L 1_T 0_R\rangle \leftrightarrow |0_L 2_T 0_R\rangle \leftrightarrow |0_L 1_T 1_R\rangle$$
.

In reverse bias, the qutrit is trapped in the dark state $|0_T\rangle$ through the transitions

Reverse:
$$|0_L 1_T 0_R\rangle \leftrightarrow |1_L 0_T 0_R\rangle \rightarrow |0_L 0_T 0_R\rangle$$
.

The first part is allowed when J' > 0, and the second part is due to the cold bath. When the qutrit is in the dark state, excitations are not allowed to propagate from the hot bath to the qutrit due to energy conservation.

IV. RESULTS

The excitation current and work results are plotted in Fig. 2(a) as the diode is turned on via an increase in J'. The current, in reverse bias, becomes suppressed, and the number of excitations added through work per unit of time is orders of magnitude smaller than the excitation current in either bias. This is further verified by Fig. 2(b) where the rectification is plotted. To verify that the current in reverse bias is indeed blocked due to the dark state being populated, we plot the dark-state population, $P_{ss}(|0_T\rangle) = \langle |0_T\rangle\langle 0_T|\rangle_{ss}$ in Fig. 2(c). The dark-state population in reverse bias does indeed approach unity as the diode is turned on.

V. MARKOVIAN SOLUTION

An analytic solution can be found for ω , $\delta\omega\gg\Gamma\gg J$, J', $J'/J\gg\Gamma/\delta\omega$, $n_C=0$, and $n_H\leqslant 1$ [12,40]. In this regime, all coherences in $\hat{\rho}$ will decay rapidly and the harmonic oscillators can be seen as baths with Lorenzian spectral densities

through the Markov approximation which for the right bath becomes

$$S_{\hat{B}}(\omega') = \frac{(1+n_R)J^2\Gamma}{(\omega-\omega')^2 + \Gamma^2/4} + \frac{n_RJ^2\Gamma}{(\omega+\omega')^2 + \Gamma^2/4}$$

Here $\hat{B}=J(\hat{a}_R^\dagger+\hat{a}_R)$ is the right harmonic oscillator operator that couples to the qutrit. The spectral density for the left harmonic oscillator is similar, but with four terms due to the driving. Using this, the populations for the qutrit $P(|\alpha_T\rangle)=\mathrm{tr}\{|\alpha_T\rangle\langle\alpha_T|\hat{\rho}\}$ can be written in the form discussed earlier, $\partial_t \vec{P}(t)=W\vec{P}(t)$. The transition rates become

$$\Gamma_{2_T \to 0_T} = 0, \quad \Gamma_{1_T \to 0_T} = \frac{(1 + n_L)J^2}{\Gamma} + \frac{(1 + n_R)J^2\Gamma}{\delta\omega^2 + \Gamma^2/2},$$
(5a)

$$\Gamma_{2_T \to 1_T} = \frac{8(1 + n_L)J^2}{\Gamma} + \frac{8(1 + n_R)J^2}{\Gamma}, \quad \Gamma_{0_T \to 2_T} = 0,$$
(5b)

$$\Gamma_{0_T \to 1_T} = \frac{n_L J^2}{\Gamma} + \frac{n_R J^2 \Gamma}{\delta \omega^2 + \Gamma^2 / 2},$$
 (5c)

$$\Gamma_{1_T \to 2_T} = \frac{8n_L J^2}{\Gamma} + \frac{8n_R J^2}{\Gamma}.$$
 (5d)

The first term in each rate is due to the left bath, while the second term is due to the right term. The solution to $W\vec{P}_{\rm ss}=0$ can be found to be

$$\vec{P}_{ss} = \mathcal{N} \begin{pmatrix} (2 + n_R + n_L) \left((1 + n_L) J'^2 + (1 + n_R) J^2 \frac{\Gamma^2}{\delta \omega^2} \right) \\ (2 + n_R + n_L) \left(n_L J'^2 + n_R J^2 \frac{\Gamma^2}{\delta \omega^2} \right) \\ (n_R + n_L) \left(n_L J'^2 + n_R J^2 \frac{\Gamma^2}{\delta \omega^2} \right) \end{pmatrix},$$
(6)

where \mathcal{N} is a constant ensuring $P_{\rm ss}(|0_T\rangle) + P_{\rm ss}(|1_T\rangle) + P_{\rm ss}(|2_T\rangle) = 1$ and we used the assumption $\delta\omega\gg\Gamma$. The current is now found as the number of excitations decaying due to the cold bath, e.g., $\mathcal{J}_{\rm f}\simeq P(|2_T\rangle)\frac{8J^2}{\Gamma}$. Since one quanta of energy $\delta\omega$ is added through work every time the left bath causes a transition between $|0_T\rangle$ and $|1_T\rangle$, the excitation work is found as the number of excitations exchanged with the left bath through the J' interaction, e.g., $\mathcal{W}_{\rm r}/\delta\omega = -P(|1_T\rangle)\frac{J^2}{\Gamma}$. Under the stated assumptions the current and work become

$$\begin{split} \mathcal{J}_{\rm f} &= \frac{8n_H^2}{2 + 5n_H + 3n_H^2} \frac{J^2}{\Gamma}, \\ \mathcal{J}_{\rm r} &= -\frac{n_H}{2 + n_H} \frac{8n_H J^2 + (2 + n_H) J'^2}{J'^2} \frac{J^2 \Gamma}{\delta \omega^2}, \\ \mathcal{W}_{\rm f} / \delta \omega &= \frac{n_H (2 + n_H)}{2 + 5n_H + 3n_H^2} \frac{J^2 \Gamma}{\delta \omega^2}, \\ \mathcal{W}_{\rm r} / \delta \omega &= -n_H \frac{J^2 \Gamma}{\delta \omega^2}. \end{split}$$

The rectification can be found to be

$$\mathcal{R} = \frac{8n_H(2+n_H)}{2+5n_H+3n_H^2} \frac{J^{\prime 2}}{8n_H J^2 + (2+n_H)J^{\prime 2}} \frac{\delta\omega^2}{\Gamma^2}.$$
 (7)

This approximate expression for the rectification and the full solution is plotted in Fig. 2(d) for different values of Γ . There is a clear overlap between the two solutions and we see that

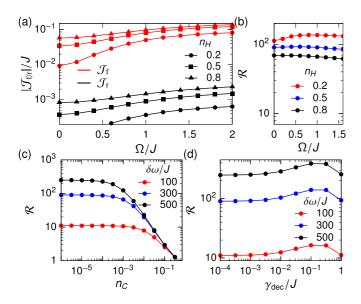


FIG. 3. (a) Forward-bias and reverse-bias current as a function of amplification Ω for different values of n_H . (b) Rectification as a function of Ω for different values of n_H . (c) Rectification as a function of n_C for different values of the anharmonicity $\delta \omega$. (d) Rectification as a function of decoherence rate $\gamma_{\rm dec}$ for different values of $\delta \omega$.

 $\mathcal{R} \propto \delta \omega^2$. Furthermore, in the limit $\delta \omega \to \infty$, this model approaches the idealized model in Figs. 1(a) and 1(b), and we achieve an ideal diode. The work both in forward and reverse biases is suppressed as $1/\delta \omega^2$, and therefore, the work done on the system is small. This is also verified from Fig. 2(a). Thus the work done acts as a catalyst and it does not contribute excitations so as to keep $\mathcal{J}_R \approx -\mathcal{J}_L$ both in forward bias and reverse bias, see Eq. (4a).

VI. AMPLIFICATION

Small excitation currents can be difficult to measure and it might be preferable to have a functioning diode with a greater heat output. Thus we might want to amplify the current through work while keeping a large rectification. This can be done by driving the transition $|1_T\rangle \leftrightarrow |2_T\rangle$ while not effecting the dark state. Since the qutrit has a large aniharmonisity, the forward-bias current can be amplified through the Hamiltonian

$$\hat{H}_{\mathrm{Amp}} = \hat{H} + rac{\Omega}{2} (\hat{a}_T e^{i\omega t} + \hat{a}_T^\dagger e^{-i\omega t}).$$

In Fig. 3(a), both the forward-bias current and the reverse-bias current are plotted as a function of the amplification Ω . Even though the driving is only resonant in forward bias, we see an increase in both the forward-bias and reverse-bias current. For a small $n_H = 0.2$, the forward-bias current is amplified by more than an order of magnitude, while the amplification is lower for larger n_H . In Fig. 3(b), the rectification is plotted as a function of the amplification Ω . The rectification changes very little as a function of Ω .

VII. ROBUSTNESS

Finally, we study the robustness towards excitations from the cold bath and decoherence. First, we let the cold bath introduce excitations by letting $n_C > 0$. The rectification is plotted in Fig. 3(c) as a function of n_C . The diode functionality is clearly diminished for larger n_C . This can be explained by looking at the reverse-bias rate

$$\Gamma_{0_T \to 1_T} = \frac{J^{\prime 2} n_C}{\Gamma} + \frac{n_H J^2 \Gamma}{\delta \omega^2}.$$
 (8)

Since this process decreases the population of the dark state, it results in a decrease in rectification. Therefore, in addition to large $\delta\omega$, we need a small n_C . The assumption $n_C=0$ is valid when $n_C\ll n_H\frac{J^2}{J^2}\frac{\Gamma^2}{\delta\omega^2}$. For the default values, this corresponds to $T_C\ll 0.16\omega$, which is achievable in current quantum technology platforms [34]. Second, we add decoherence in the form of decay and dephasing to the qutrit. This is done through an updated Liouvillian

$$\mathcal{L}_{\text{dec}}[\hat{\rho}] = \mathcal{L}[\hat{\rho}] + \gamma_{\text{dec}}(\hat{a}_T \hat{\rho} \hat{a}_T^{\dagger} - \frac{1}{2} \{\hat{a}_T^{\dagger} \hat{a}_T, \hat{\rho}\})$$
$$+ \gamma_{\text{dec}}(\hat{a}_T^{\dagger} \hat{a}_T \hat{\rho} \hat{a}_T^{\dagger} \hat{a}_T - \frac{1}{2} \{\hat{a}_T^{\dagger} \hat{a}_T \hat{a}_T^{\dagger} \hat{a}_T, \hat{\rho}\}),$$

where $\mathcal{L}[\hat{\rho}]$ is the Liouvillian from Eq. (1). This results in decay and dephasing coherence times of $T_1 = T_2 = \gamma_{\rm dec}^{-1}$ for the lowest two states. On the other hand, the second excited state of the qutrit has decay coherence time $T_1 = \gamma_{\rm dec}^{-1}/2$. In Fig. 3(d), the rectification is plotted as a function of the decoherence $\gamma_{\rm dec}$. State-of-the-art quantum platforms can achieve $\gamma_{\rm dec}/J < 10^{-3}$ [41]. However, the dark-state-induced rectification is clearly not sensitive to decoherence, and other parameters can be focused on, e.g., a larger anharmonicity can be picked even if it results in larger decoherence. The stability of the rectification towards decoherence is clearly a result of the dark state being the qutrit ground state.

VIII. WORK TO OPEN AND CLOSE DIODE

Even though approximately no work is done in the steady state, driving plays a vital role in closing and opening the diode. Therefore, work is done when the temperature bias is inverted. To study the work performed during the transition from the steady state $\hat{\rho}_r$ to $\hat{\rho}_f$, the system is prepared in $\hat{\rho}_r$ at t=0 and then evolved with respect to the forward-bias Lindblad superoperator. The work done by the driving is plotted in Fig. 4(a). The same is done starting in the steady state $\hat{\rho}_f$ and evolving with respect to the reverse-bias Lindblad superoperator. As expected, it requires work for the diode to switch between the steady states. Next we calculate the total energy added or subtracted through work during the transition of the diode. The total work done to transition from the reverse-bias steady state to the forward-bias steady state is

$$W_{r\to f} = \int_0^{t_{\text{turn}}} \mathcal{W}(t) dt,$$

where t_{turn} is the time for the diode to go from closed to open or the reverse. We set $t_{\text{turn}} = 500J^{-1}$. This total work is plotted in Fig. 4(b). As a comparison, we also plot

$$\Delta P_{\rm ss}(|0_T\rangle) = P_{\rm ss,r}(|0_T\rangle) - P_{\rm ss,f}(|0_T\rangle).$$

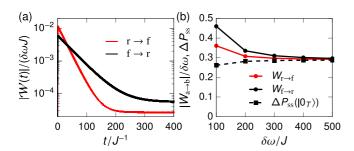


FIG. 4. (a) Work for an initial state of $\hat{\rho}_{r(f)}$ and evolved with respect to the forward (reverse) bias Lindblad super operator. (b) Total work performed to transition the diode and population difference $\Delta P_{ss}(|0_T\rangle) = P_{ss,r}(|0_T\rangle) - P_{ss,f}(|0_T\rangle)$ as a function of $\delta\omega$.

This is the population that has to be transferred for the diode to switch from closed to open. For $\delta\omega=100J$, more work is done than is needed to make the transition possible. For larger $\delta\omega$, both $W_{\rm r\to f}$ and $W_{\rm f\to r}$ approach the total work needed for the transition $\Delta P_{\rm ss}(|0_T\rangle)$.

IX. CONCLUSION

We introduced a class of rectifiers that exploit the unidirectionality of a cold thermal bath to trap the system in a dark state in reverse bias. In the ideal case, the dark state is completely isolated from the hot bath and infinite rectification is achieved. Furthermore, we realized the ideal model using a single qutrit interacting with two baths mediated by two harmonic oscillators. The two harmonic oscillators transform the baths spectral densities into a sum of Lorentzians allowing for dark-state-induced rectification. We showed that rectification factors beyond 10³ can be achieved, and we found an approximate expression for the currents, work, and rectification. The currents can be amplified by up to an order of magnitude by driving the transition $|1_T\rangle \leftrightarrow |2_T\rangle$. We showed that the rectification is stable within achievable cold bath temperatures and towards a large degree of decoherence. Finally, we found the work needed to transition the diode from forward to reverse bias and the reverse.

The model is simple and generic and should be realizable using several of the current quantum technology platforms like germanium quantum dots [42], trapped ions [43], Rydberg atoms [44], or superconducting circuits [41,45–47]. In superconducting circuits, the model can be implemented using a single transmon coupled capacitively to two wave guides. The waveguide correlation functions can be forced to decay using resistors [47]. The amplification can be implemented by driving the transmon through a time-dependent flux or through capacitive driving [45].

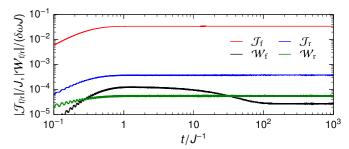


FIG. 5. Currents and work as a function of time in both forward and reverse bias. Here $\delta\omega=300, J'=0.5J, \Gamma=10J, n_H=0.5$, and $n_C=0$.

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APPENDIX: NUMERICAL METHODS AND CONVERGENCE OF THE EXCITATION CURRENT

In the main text, we studied the properties of the steady-state. However, due to the time-dependent Hamiltonian the steady state will not obey $\partial_t \hat{\rho} = 0$, and it cannot be found through diagonalization. Instead, the state is evolved in time until the current and work converge. The initial state is picked to be diagonal with the approximate populations found in the main text. The harmonic oscillators are truncated such that the highest excited state $|m_{\text{max}}\rangle$ has $P_{\text{th}}(|m_{\text{max}}\rangle) < 10^{-3}$ where $m_{\text{max}} \in \{0, 1, 2, 3, \dots, \}$. Furthermore, $P_{\text{th}}(|m\rangle)$ is the population of $|m\rangle$ in the harmonic-oscillator thermal state

$$P_{\text{th}}(|m\rangle) = \frac{\text{tr}\{|m\rangle\langle m|e^{-\omega/T\hat{a}^{\dagger}\hat{a}}\}}{\text{tr}\{e^{-\omega/T\hat{a}^{\dagger}\hat{a}}\}} = \frac{n^m}{(1+n)^{m+1}},$$
where $n = (e^{\omega/T} - 1)^{-1}$.

The highest kept excited state can then be found to be

$$m_{\text{max}} = \left\lceil \frac{\ln\{(n+1)10^{-3}\}}{\ln n - \ln(n+1)} \right\rceil,$$

where $\lceil \bullet \rceil$ is the function that returns the smallest integer greater then or equal to the input. In Fig. 5, the currents and work are plotted as a function of time for both forward and reverse biases. We see that all four quantities converge for larger times. In all simulations performed for the results in the main text, the density matrix was evolved for a time $t_{\text{final}} = 5000J^{-1}$ and the quantities are averaged over times $t = 4900J^{-1} - 5000J^{-1}$.

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